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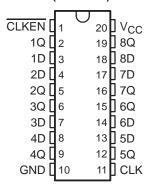
- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 1 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C
- High-Drive Outputs (-32-mA I<sub>OH</sub>, 64-mA I<sub>OL</sub>)
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), Plastic (N) and Ceramic (J) DIPs, and Ceramic Flat (W) Package

#### description

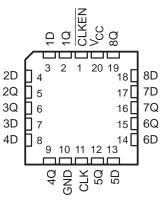
These 8-bit positive-edge-triggered D-type flip-flops with a clock (CLK) input are particularly suitable for implementing buffer and storage registers, shift registers, and pattern generators.

Data (D) input information that meets the setup time requirements is transferred to the Q outputs on the positive-going edge of the clock pulse if the common clock-enable (CLKEN) input is low. Clock triggering occurs at a particular voltage level and is not directly related to the transition time of the positive-going pulse. When the buffered clock (CLK) input is at either the high or low level, the D-input signal has no effect at the output. The circuits are designed to prevent false clocking by transitions at CLKEN.

SN54ABT377 . . . J OR W PACKAGE SN74ABT377A . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



SN54ABT377 . . . FK PACKAGE (TOP VIEW)



The SN54ABT377 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74ABT377A is characterized for operation from  $-40^{\circ}$ C to 85°C.

### FUNCTION TABLE (each flip-flop)

l)	INPUTS					
CLKEN	CLK	D	Q			
Н	Х	Χ	Q <sub>0</sub>			
L	$\uparrow$	Н	Н			
L	$\uparrow$	L	L			
Х	H or L	Χ	$Q_0$			



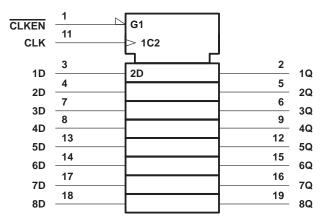
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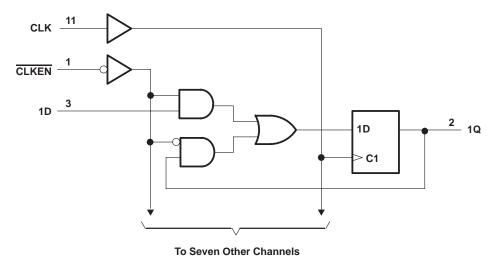
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### logic symbol†



 $<sup>\</sup>ensuremath{^{\dagger}}$  This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

#### logic diagram (positive logic)



TEXAS INSTRUMENTS

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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		
Voltage range applied to any output in the high	or power-off state, VO	
Current into any output in the low state, IO: SN	54ABT377	96 mA
		128 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)		
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)		
Package thermal impedance, θ <sub>JA</sub> (see Note 2):	DB package	
	DW package	97°C/W
	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.

#### recommended operating conditions (see Note 3)

			SN54A	BT377	SN74AB	T377A	UNIT
			MIN	MAX	MIN	MAX	ONIT
V <sub>CC</sub> Supply voltage		4.5	5.5	4.5	5.5	V	
V <sub>IH</sub> High-level input voltage		2		2		V	
V <sub>IL</sub> Low-level input voltage			0.8		0.8	V	
V <sub>I</sub> Input voltage		0	Vcc	0	VCC	V	
loh	High-level output current			-24		-32	mA
lOL	I <sub>OL</sub> Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		5		5	ns/V
TA	Operating free-air temperature	g free-air temperature		125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.



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## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		T,	A = 25°C	;	SN54ABT377		SN74ABT377A		UNIT	
PARAMETER			MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT	
VIK	$V_{CC} = 4.5 \text{ V},$	I <sub>I</sub> = -18 mA				-1.2		-1.2		-1.2	V
	$V_{CC} = 4.5 \text{ V},$	$I_{CC} = 4.5 \text{ V}, \qquad I_{OH} = -3 \text{ mA}$		2.5			2.5		2.5		
Vari	$V_{CC} = 5 \text{ V}, \qquad I_{OH} = -3 \text{ mA}$			3			3		3		V
VOH	V00 - 45 V	$I_{OH} = -24 \text{ mA}$		2			2				V
	V <sub>CC</sub> = 4.5 V	$I_{OH} = -32 \text{ mA}$		2*					2		
Vai	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA				0.55		0.55			V
VOL	vCC = 4.5 v	I <sub>OL</sub> = 64 mA				0.55*				0.55	V
V <sub>hys</sub>					100						mV
lį	$V_{CC} = 5.5 \text{ V},$	$V_I = V_{CC}$ or $GN$	D			±1		±1		±1	μΑ
l <sub>off</sub>	$V_{CC} = 0$ ,	V <sub>I</sub> or V <sub>O</sub> ≤ 4.5 V	1			±100				±100	μΑ
ICEX	$V_{CC} = 5.5 \text{ V},$	V <sub>O</sub> = 5.5 V	Outputs high			50		50		50	μΑ
IO <sup>‡</sup>	$V_{CC} = 5.5 V$ ,	V <sub>O</sub> = 2.5 V		-50	-100	-180	-50	-180	-50	-180	mA
laa	V <sub>CC</sub> = 5.5 V, I <sub>C</sub>	) = 0,	Outputs high		1	250		250		250	μΑ
Icc	1		Outputs low		24	30		30		30	mA
Δl <sub>CC</sub> §	$V_{CC}$ = 5.5 V, One input at 3.4 V, Other inputs at $V_{CC}$ or GND				1.5		1.5		1.5	mA	
C <sub>i</sub>	V <sub>I</sub> = 2.5 V or 0.	5 V			3.5						pF

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter does not apply.

# timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

				SN54ABT377				
			V <sub>CC</sub> =	= 5 V, 25°C	MIN	MAX	UNIT	
			MIN	MAX				
fclock	Clock frequency		0	150	0	150	MHz	
t <sub>W</sub>	Pulse duration	CLK high or low	3.3		3.3		ns	
+.	Setup time before CLK↑	Data high or low	2		2.5		ne	
t <sub>su</sub>	Setup time before CLK	CLKEN high or low	3		3		ns	
+.	Hold time after CLK↑	Data high or low	1.8¶		1.8¶		nc	
<sup>t</sup> h	noid tille after CEXT	CLKEN high or low	1.8¶	·	1.8¶		ns	

This data sheet limit may vary among suppliers.

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ .

<sup>‡</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

<sup>§</sup> This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.

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# timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

					SN74ABT377A				
			V <sub>CC</sub> =	= 5 V, 25°C	MIN	MAX	UNIT		
			MIN	MAX					
f <sub>clock</sub>	f <sub>clock</sub> Clock frequency			150	0	150	MHz		
t <sub>W</sub>	Pulse duration	CLK high or low	3.3		3.3		ns		
T .	Saturatima hafara CLV <sup>↑</sup>	Data high or low	2		2.5		ns		
เรน	t <sub>SU</sub> Setup time before CLK↑	CLKEN high or low	3		3		115		
4.	Hold time after CLK↑	Data high or low	1.8†		1.8†		no		
l th	Hold time after CEKT	CLKEN high or low	1.2†		1.2†		ns		

<sup>†</sup> This data sheet limit may vary among suppliers.

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
fmax			150			150		MHz
t <sub>PLH</sub>	CLK	Q	2.2	4.5	6	2.2	7	ns
t <sub>PHL</sub>	CLK		3.1	5.3	6.8	2	7.6	115

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

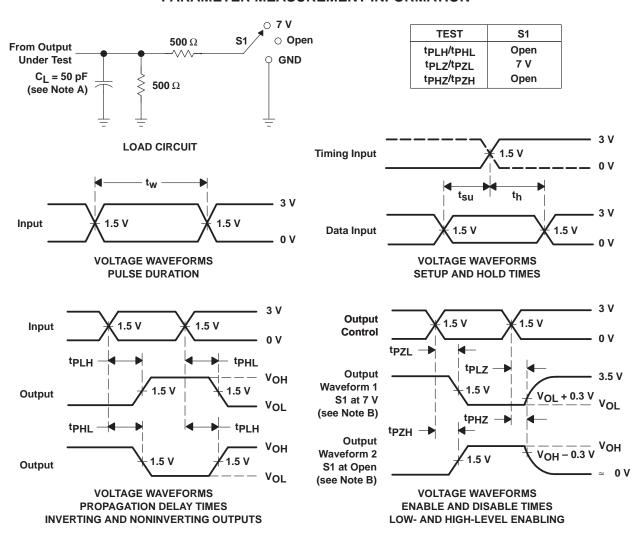
				SN7	4ABT37	77A		
PARAMETER	FROM TO (OUTPUT)	TO (OUTPUT)	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C		MIN	MAX	UNIT	
			MIN	TYP	MAX			
f <sub>max</sub>			150			150		MHz
<sup>t</sup> PLH	CIK	Q	2.2	4.5	6	2.2	6.5	ns
<sup>t</sup> PHL	CLK		2.6†	5.3	6.8	2.6†	7.3	115

<sup>†</sup> This data sheet limit may vary among suppliers.



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#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2.5 ns,  $t_f \leq$  2.5 ns,
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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